Fast Recovery Diodes (FRD)

Panasonic

MA3D690 (MA6D90)

Silicon planar type

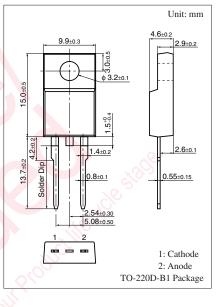
For high-frequency rectification

Features

- \bullet Low forward voltage $V_{\rm F}$
- Fast reverse recovery time t_{rr}
- TO-220D (Full-pack package) with high dielectric breakdown voltage
- Easy-to-mount, caused by its V cut lead end

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Symbol	Rating	Unit
V _{RRM}	200	V
V _{RSM}	200	V
I _{F(AV)}	5	А
I _{FSM}	30	A
Tj	-40 to +150	°C
T _{stg}	-40 to +150	°C
	V _{RRM} V _{RSM} I _{F(AV)} I _{FSM} T _j	$ \begin{array}{c c} V_{RRM} & 200 \\ V_{RSM} & 200 \\ I_{F(AV)} & 5 \\ I_{FSM} & 30 \\ T_{j} & -40 \text{ to } +150 \\ \end{array} $

Absolute Maximum Ratings $T_a = 25^{\circ}C$



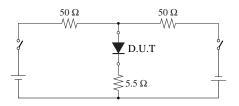
Note) *: 50 Hz sine wave 1 cycle (Non-repetitive peak current)

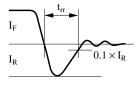
Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V _F	$I_F = 5 \text{ A}, T_C = 25^{\circ}\text{C}$	No.		0.98	V
Repetitive peak reverse current	I _{RRM1}	$V_{RRM} = 200 \text{ V}, T_{C} = 25^{\circ}\text{C}$	O.X		20	μΑ
	I _{RRM2}	$V_{RRM} = 200 \text{ V}, \text{ T}_{j} = 150^{\circ}\text{C}$			2	mA
Reverse recovery time *	t _{rr}	$I_F = 1 A, I_R = 1 A$			45	ns
Thermal resistance (j-c)	R _{th(j-c)}				3.0	°C/W
Thermal resistance (j-a)	R _{th(j-a)}	is when			63	°C/W

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

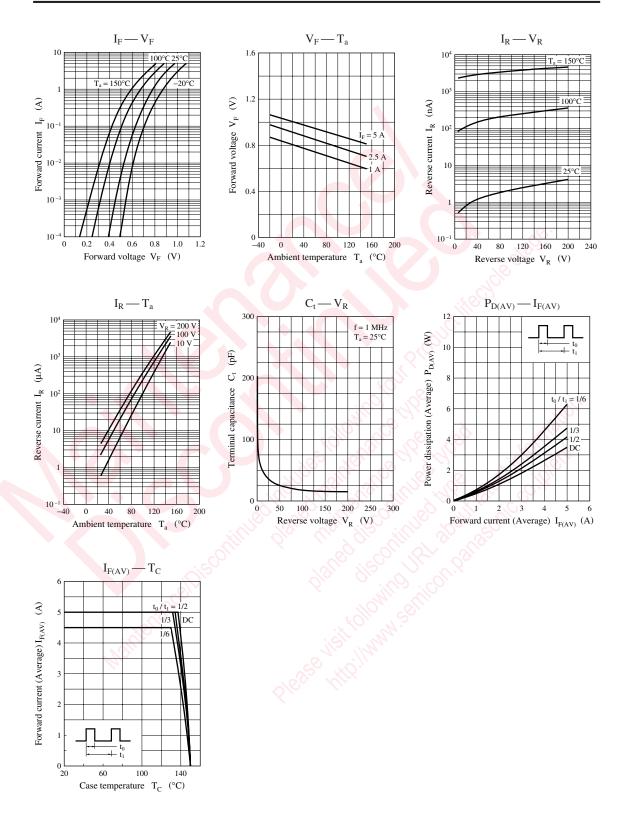
- 2. Absolute frequency of input and output is 10 MHz.
- 3. *: t_{rr} measurement circuit





Note) The part number in the parenthesis shows conventional part number.

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